Andreev current in nite sized carbon nanotubes

Sm itha V ishveshwara¹, C ristina Bena¹, Leon Balents¹, M atthew P.A.F isher²

¹Department of Physics, University of California, Santa Barbara, CA 93106

² Institute for Theoretical Physics, University of California, Santa Barbara, CA 93106{4030

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W e investigate the e ect of interactions on A ndreev current at a norm al-superconducting junction when the norm alphase is a Luttinger liquid with repulsive interactions. In particular, we study the system of a nite sized carbon nanotube placed between one m etallic and one superconducting lead. W e show that interactions and nite size e ects give rise to signi cant deviations from the standard picture of Andreev current at a norm al-superconductor junction in the nearly perfect Andreev limit.

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In recent years, the behavior of superconductors (SC) in contact with Luttinger liquids (LLs) has commanded attention in both theory [1,2] and experiment [3,4]. Josephson junctions made by sandwiching a Luttinger liquid between two superconductors have led to intriguing results such as critical currents orders of m agnitude larger than expected [3]. Experim ental study of Andreev physics at a niobium superconductor { carbon nanotube junction [4] has yielded signi cant deviation at low tem peratures from the standard picture of Andreev current in a non-interacting one-dim ensional electron gas { superconductor junction [5]. As it has been predicted [6] and shown [7] that single-walled metallic carbon nanotubes (NT) exhibit Luttinger liquid behavior, system atic analyses of any set-up involving their electronic properties would require taking into account the e ect of interactions.

Here we study the Andreev physics in a SC-NTmetallic lead junction, focusing on the e ects of the strong repulsive interactions and of the nite size of the nanotube. W e focus on energy scales well below the energy gap of the superconductor. Thus, throughout the energy range of interest (i.e for all the values of tem perature or of the applied voltages we consider), the only excitations allowed to exit or enter the superconductor are Cooper pairs and not single electrons. In particular we focus on the lim it of alm ost perfect Andreev re ection at the SC -NT interface (i.e. very low norm albackscattering). We also assume that the nanotube-metal contact is ideal and that the nanotube continues adiabatically into the m etallic lead. Under these assumptions we study how a sm all am ount of backscattering at the SC-NT interface would in uence the electrical properties of the junction, in particular the behavior of the conductance.

The treatment we use to obtain the value of the current as a function of the applied voltage is a non-equilibrium K eldysh technique, perturbative in the bare backscattering strength 'u' [9,11]. Characteristic of Luttinger liquids, the amount of backscattering can strongly increase when the energy at which the system is probed decreases. Hence, perturbation theory holds good only above an en-

 $_0$ (u= $_0$)^{2=(1 g)}, where g m easures the inergy scale E _c teraction strength (g = 1 in the absence of interactions).Form etallic nanotubes, 0 1eV is the sub-band spacing [6], and q 0:25 [6,7], corresponding to strong repulsive interactions. In the set-up considered here, the e ect of the nite length L of the nanotube becomes in portant below the nite size energy scale hv=L. Here, $v = v_F = g$ is the velocity of the charge-carrying quasiparticles in the 10^m =s is the Ferm ivelocity. Efnanotube, where $v_{\rm F}$ fects of nite size can be captured in the perturbative approach, as done here, provided hv=L E_c.

To summarize our results, a numerical analysis reveals that at zero temperature, the conductance shows a marked drop with decreasing voltage as a consequence of LL physics, consistent with renorm alization group arguments similar to the ones derived in [2]. At voltages much smaller than the nite size energy hv=L, the conductance levels o to a constant. In addition, it exhibits small spikes with a voltage spacing of hv=2L (about 2 3m eV for a nanotube of micron length), reminiscent of resonance peaks from quasi-bound states for charge carriers con ned within the length of the tube.

We now present the explicit calculation yielding the conductance as a function of applied voltage for the SC – NT -m etal system described above. The s-wave SC lies in the region x < 0 and we assume it to be ideally contacted to a nite size nanotube of length L in the region 0 < x < L which continues adiabatically into a metallic lead for x > L. We model the system in the sem i-in nite region x > 0, as a four channel LL with interaction param eters appropriate for the nanotube up to x = L, and appropriate for no interactions for x > L. The bosonized H am iltonian for this system in the absence of any norm al backscattering is given by

$$H_{0} = \int_{0}^{2} dx \int_{a}^{X} v_{a}(x) \left[\frac{1}{g_{a}(x)} (\theta_{x a})^{2} + g_{a}(x) (\theta_{x a})^{2}\right]:$$
(1)

For simplicity, we have set the constants $h = e = k_B = 1$. Note that a = correspond to the four free sectors of the theory and are obtained by linear transform ations from the spin-channel indices (1";1#;2";2#) [6]. The relation between the bosonic elds $_{i}$, $_{i}$ (i = 1=2; = " = #) and the original chiral right-/left-m oving electron elds $_{iR=L}$ is expressed through the bosonization procedure via the transformation $_{iR=L}$ $e^{i(i \ i \)}$. In the nanotube region 0 < x < L where interactions are present in the net charge density +, we take $g_{+}(x) = g$ 25, and g; = 1. A lso, in the non-interacting region x > L, we take $g_{a}(x) = 1$ for all a's. The velocities of the free m odes are given by $v_{a}(x) = v_{F} = g_{a}(x)$. The total charge density is tot = $2e_{x} + e^{-i(x)}$.

In the alm ost perfect Andreev lim it, the electrons incident from the nanotube side on the SC-NT interface re ect back as holes with opposite spin: $_{\rm iL "=\#}(0) = _{\rm iR \#="}^{\rm y}(0)$ and $_{\rm iR "=\#}(0) = _{\rm iL \#="}^{\rm y}(0)$, where i refers to the channel indices 1 and 2. In the bosonized language, these boundary conditions become (0) = 0and (0) = 0.

The weak norm all backscattering at the SC-NT junction can be modeled by modifying the Ham iltonian to $H = H_0 + H^0$, with:

$$H^{0} = \frac{u}{8} X X [\int_{iR}^{y} (0) \int_{iL} (0) + hc:]$$
$$= u \cos[+ (0)]\cos[(0)]; \qquad (2)$$

where the bosonized form takes into account the Andreev boundary conditions at the SC -NT interface. For sim plicity, we choose not to include the backscattering processes where particles can ip their band index since these terms do not give rise to any new physics.

Following Ref. [11], we integrate out the variables in the action, as well as the entire x-dependence away from x = 0. The resulting unperturbed in aginary time Euclidean action becomes

$$S_{0}^{E} = \frac{1}{n} \frac{X}{g(!_{n})} \frac{j!_{n}j}{j_{+}} (!_{n})f + \frac{1}{n} \frac{X}{j!_{n}jj_{-}} (!_{n})f; (3)$$

where is inverse temperature. Here the imaginary time Fourier transforms for all $_{R}$ edds 'A' are dened in the standard fashion A (!_n) = $_{0}$ d 0 A (0)e^{i!_n°, !_n = 2 n= . The spatial variations of the interaction parameter g(x) and of the velocity v(x) are rejected by the fact that the elective interaction parameter g(!_n) is frequency dependent and has the form :}

$$g(!_{n}) = \frac{g(1 \quad y)^{2}}{1 \quad 4gy \quad \frac{2}{y}}, \text{ with } y = \frac{1 \quad g}{1 + g} e^{-j!_{n}} \dot{j}; \quad (4)$$

Here = 2L=v is the time it takes a charge-carrying quasiparticle with velocity v to bounce back and forth between the ends of the tube. The lim its $L_i!_n ! 0$ and $L_i!_n ! 1$ retrieve the expected form $g(!_n) = 1$ and $g(!_n) = g$ for a sem i-in nite Ferm i liquid and a sem i-in nite nanotube respectively [10].

A long the lines of Ref. [11], we proceed to construct a real time K eddysh action. We introduce $_{a}$ edds nunning over forward and backward paths in time. We de ne $_{a} = (_{a}^{+} + _{a})=2$ and $a = _{a}^{+} _{a}$. The resulting action is S = S₀ + S₁ + S₂ where S₀ is the unperturbed action, S₁ describes the e ect of the weak backscattering at the SC-NT interface, and S₂ captures the e ect of applying a chemical potential di erence V = $@_{t}a$. Thus

$$S_{0} = \begin{bmatrix} Z & \frac{d!}{2} & \frac{1}{2} \left[\frac{1}{g(!)} + \frac{1}{g(-!)} \right] \operatorname{oxth} \frac{1}{2T} j^{*}_{+} (!) j^{2}_{+} + \begin{bmatrix} \frac{d!}{g(!)} & \frac{1}{g(!)} & \frac{1}{g(!)} \\ + \frac{d!}{2} & \frac{1}{2} \operatorname{oxth} \frac{1}{2T} j^{*}_{-} (!) j^{2}_{+} + \frac{d!}{2} & \frac{1}{2} & (!) & (-!); \\ S_{1} = \inf \operatorname{dtfcos}[^{+}_{+} (t)] \operatorname{cos}[^{+} (t)] & \operatorname{cos}[_{+} (t)] \operatorname{cos}[(t)]g; \\ S_{2} = \begin{bmatrix} Z & \frac{2!}{2} \left[a(!)^{*}_{+} (-!) + (!) + (-!) \right]; \\ \end{bmatrix}$$

where g(!) is the analytically continued version of g(!_n) in Eq.(4) with $j!_n$ j replaced by i! . For all elds 'A', we have used the real time Fourier transform convention A (!) = dtA (t)e^{i!t}. The source eld allows for calculation of the current, I (t) = $2-_+$ (t) = (i=2) (S = (t)j_{=0}). A verage quantities may be derived by taking expectation values with respect to the K eldysh generating functional, $Z = D [+D] e^{S}$.

Using the above Keldysh action, and treating the backscattering to lowest non-vanishing order in perturbation, we nd the expectation value of the current to be

$$I = 8 \frac{e^2}{h} V \qquad I_{\rm B} ; \qquad (6)$$

(5)

where from here on, we reinsert factors of e;h and $k_{\rm B}$. The rst term is associated with the constant conductance G $_0$ = $8\frac{e^2}{h}$ in the absence of backscattering. As expected, this ideal Andreev conductance of the nite size nanotube in the presence of a metallic lead is that of a four mode non-interacting 1D electron gas [1,10]. The backscattering current $I_{\rm B}$ takes the form :

$$I_{B} = \frac{e}{2} \frac{u}{h} \int_{0}^{2^{L} 1} dt \sin \frac{2eVt}{h} e^{[C(t) C(0)]} \sin [R(t)]; (7)$$

In the above equation, $C(t) = P_{a=} C_a(t)$ and $R(t) = R_a(t) R_a(t) = 2$. For each mode, $C_a(t)$ and $R_a(t)$ are the correlation and response functions respectively, with $C_a(t) = h_a(t)_a(0)i_0$ and $R_a(t) = ih_a(t)^a_a(0)i_0$. Their Fourier transforms are related by the uctuation-dissipation theorem, $C_a(!) =$ $oth \frac{h!}{2k_B T}$ Im $R_a(!)$]. Here averages are with respect to the unperturbed action, and we have $R_+(!) =$

i g(!) = ! and R (!) = i = !We now p ake a series expansion of $g(!_n)$ in Eq.(4), $g(!_n) = g_{n-n}y^n$. When analytically continued, this gives:

$$g(!) = g_{n=0}^{X^{i}} \frac{1 g^{n}}{1 + g} e^{in!} :$$
 (8)

Substituting the above in Eq.(7) and taking the derivative with respect to the applied voltage gives the follow-ing reduction in the conductance due to backscattering $G_B = \frac{dI_B}{dV}$, in the limit T ! 0:

$$G_{B} = 2\frac{e^{2}}{h} \frac{u}{h} \sum_{k=0}^{2X^{k}} \frac{X^{k}}{n=0} \sum_{n=0}^{2(k+1)} dxx \frac{\cos[2eV x = h]}{[1 + (_{0}x = h)^{2}]^{\circ}} \sum_{n=1}^{Y^{k}} \frac{x}{n} \sum_{n=1}^{2} 1^{n};$$
(9)

where the coe cients n = g(n=2)[(1 g)=(1+g)], for n > 0, and 0 = (1+g)=2. We have used the high energy cut-0 = 0 to evaluate the Fourier transform s C_a (t) and R_a (t). Here the terms involving n correspond to physical processes of n bounces of the quasiparticles at the boundaries of the nanotube. Note that besides the weak backscattering at the SC-NT interface, the quasiparticles can also backscatter at the nanotube metallic lead junction even in the absence of a barrier, solely as a result of the m ism atch of the values of the net charge and velocity of the free modes in the nanotube and in the m etal.

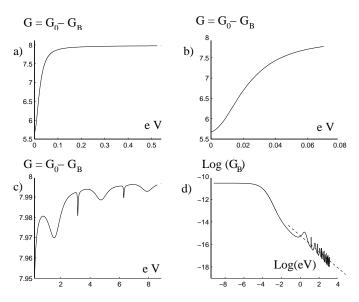


FIG.1. The net di erential conductance G = dI=dV of the nanotube set-up in units of $e^2=h$ as a function of applied voltage eV in units of h=. The values of the parameters are g = 25, u = 300 (h=) and $_0 = 10^5$ (h=). a), b) and c) show the conductance for di erent ranges of applied voltage. The log-log plot of G_B in d) shows a constant at low voltages and a power law G_B V^{g 1} on average for high voltages, as indicated by the dashed line.

The most revealing analysis of Eq.(9) com es from numericalevaluation. We restrict the in nite sum sofEq.(9)to a nite num ber of terms, and introduce an explicit high energy cuto 0, in order to regulate singularities. We ensure that errors com ing from both truncations are negligible. In Fig.1, we plot the net di erential conductance $\frac{dI}{dV}$ = G $_0$ G $_B$, as the one of experimental relevance. The conductance drops with decreasing voltage and levels o at voltagesm uch sm aller than h= . To see why thism ight be expected, notice that at large voltages eV h= ,the time scale at which the system is probed is much shorter than , and the conductance roughly behaves as if the nanotube were sem i-in nite. Characteristic of Luttinger liquid physics, it thus drops as $G_B / u^2 (2geV = _0)^{g-1}$ on average, as shown in Fig. 1 d). This limiting behavior can be seen directly in Eq.(9) by taking ! 1. At h= , the associated time scale is long low voltages eV enough to capture the e ect of the metallic lead and of multiple backscattering events at its interface. With decreasing voltage, the conductance ultim ately levels o to a constant, as per 0 hm 's law for the m etallic lead. This lim it can be obtained in Eq.(9) by setting = 0.

A striking feature of the plots is the presence of spikes at probe values eV = nh = , w ith 'n' being an integer.As their magnitude is minuscule compared to the net variation in conductance, it would be di cult to measure them in experiment. However, these resonances do exist, and are signatures of the quasi-bound states that one would expect within the nanotube region, given that here the interaction parameter and velocity are di erent from those of the metallic lead.

As a variation of the above set-up, let us now replace the nanotube by a nite sized Luttinger liquid with only two transport channels (spin " = #). Such a situation can be realized by using, for instance, an etched quantum wire. The corresponding free modes carry net charge and spin , and are linear combinations of the two spin species. And rev boundary conditions at the superconducting junction require (0) = 0; (0) = 0 in

corresponding bosonized variables. Thus, the system can be e ectively described by a single channel in the variables. This allows for us to study the particular situation where the velocity of the charge mode in the Luttinger liquid $v = v_F = q w$ ould equal the Ferm ivelocity v_F^1 in the m etallic lead, i.e $v_F^1 = v_F = g$. Hence, we can focus on the physics arising purely from the mism atch of the charge of the elementary excitations in the Luttinger liquid and the lead. This would not have been possible for the case of the nanotube as it is described by two modes moving at di erent velocities, and m atching the velocity of one mode to the Ferm i velocity of the metallic lead would cause a velocity m ism atch in the other m ode. W e calculate the conductance as a function of applied voltage for this system in a manner completely analogous to the one described above for the nanotube. The major di erence here is that we have only one mode with e ective interaction param eter

$$g(!_n) = \frac{g}{1 \quad (1 \quad g) \exp(j!_n)}$$
: (10)

The resulting conductance is plotted in Fig. 2. The magnitude of the resonances at eV = nh = spans a larger fraction of the net variation in conductance com – pared to the case of the nanotube. It is noteworthy that these resonances exist in spite of the fact that there is no m ism atch of velocities of the free phonon m odes in the Luttinger liquid and in the m etal. As expected, the phonons rebound at the Luttinger liquid-m etal interface solely due to the impedance m ism atch in the charge sector.

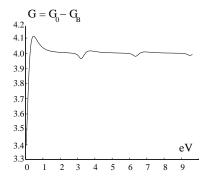


FIG.2. The net conductance G of the two-m ode Luttinger liquid set-up in units of e^2 =h as a function of applied voltage eV in units of h= . The values of the parameters are g = .25, u = 1.4 (h=) and _0 = 10⁴ (h=).

To sum marize, we have boked at how the standard picture for Andreev current through a superconductorm etallic wire junction gets altered in the Andreev lim it in the presence of interaction and nite size e ects. The Andreev conductance shows a reduction with decreasing voltage which nally levels o at the low est voltages. Finite size e ects also give rise to resonances manifest as sm all spikes in the conductance.

Finally, turning to experiment, while Luttinger liquid behavior in nanotubes contacted to normal leads has been analyzed in great detail [7], by no means has it been studied system atically in the presence of superconducting leads. As seen here, one would certainly expect Luttinger liquid e ects to yield signi cant deviations from the standard picture of Andreev physics for noninteracting one-dimensional wires. Consistent with our assum ptions, such experim ents can be perform ed, for example, in superconductor-nanotube junctions, in which the superconducting gap energy is of the order of several meV, while for a nanotube of a few microns, the nite size energy is in the range of a m eV. At tem peratures of the order of 100m K, therm ale ects are expected to be negligible. These conditions are well within experim ental reach, and system atic analyses of such set-ups could potentially reveal rich physics arising from bringing Luttinger liquids in contact with superconductors.

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